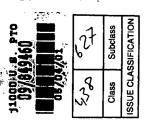
	クレン	
•	ť	_
١		ز



l	PATENT	NUMBER
ı		
ı		

U.S. **UTILITY** Patent Application

SOANNED CO.I.P.E. PATENT DATE

APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/849460	F	438	12-7	2812	Variable
	1		، ناھا	المسد	4600 KW

Teng-Tang Yang Kun-Yi Lu Ying-Chang Chia Jiin-Shiarng Wen

Process for forming a conducting structure layer that can reduce metal etching residue

PTO-2040 12/99

ISSUING CLASSIFICATION								
ORIGINAL	,	CROSS REFERENCE(S)						
CLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)						
438	627	438	689	629	637	638	639	640
*INTERNATIONAL CLASSIFICATION		438	668	672	675	677		
401L 21	1/4763							
	/	•						
3								
				☐ Continued on Issue Slip Inside File Jacket				

TERMINAL	DRAWINGS			CLAIMS ALLOWED		
DISCLAIMER,	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.	
	5	9	3E	19	/	
☐ The term of this patent	(Assistant Examiner) (Date)		NOTICE OF ALI	LOWANCE MAILED		
subsequent to (date) has been disclaimed.			(Date)			
☐ The term of this patent shall						
not extend beyond the expiration date of U.S Patent. No				ISSUE FEE		
				Amount Due	Date Paid	
	(Primary Examiner) (Date)					
☐ The terminalmonths of				ISSUE BA	TCH NUMBER	
this patent have been disclaimed.	(Legal Instruments Examiner) (Date)					
WARNING:						
The information disclosed herein may be rest Possession outside the U.S. Patent & Tradem	ricted. Unauthorized of ark Office is restricted	lisclosure may be p to authorized emplo	prohibited by the U byees and contract	nited States Code Title 3 ors only.	5, Sections 122, 181 and 368	
orm PTO-436A Nev. 6/99)			FILED WITH:	DISK (CRF)	FICHE CD-RO	